

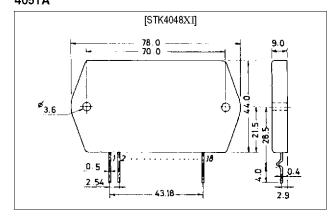
AF Power Amplifier (Split Power Supply) (150W min, THD = 0.008%)

Features

- The use of a current mirror circuit, cascode circuit, pure complementary circuit provides low distortion (THD= 0.008%/100kHz LPF ON).
- Possible to design electronic supplementary circuits (pop noise muting at the time of power ON/OFF, load short protector, thermal shutdown)

Package Dimensions

unit: mm **4051A**



Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		±87	٧
Thermal resistance	Өј-с	Per power Transistor	1.2	°C/W
Junction temperature	Tj		150	°C
Operating substrate temperature	T _C		125	°C
Storage temperature	Tstg		-30 to +125	°C

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		±60	٧
Load resistance	RL		8	Ω

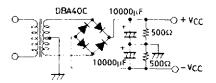
$\label{eq:characteristics} \mbox{ at Ta} = 25^{\circ} \mbox{C}, \ V_{CC} = \pm 60 \mbox{V}, \ R_{L} = 8 \mbox{\Omega}, \ VG = 40 \mbox{dB}, \ Rg = 600 \mbox{\Omega}, \ 100 \mbox{kHz LPF ON}, \ R_{L}: \ noninductive \ load$

Parameter	Symbol	Conditions	min	typ	max	Unit
Quiescent current	lcco	V _{CC} = ±72V	15		120	mA
Output power	Ро	THD = 0.008%, f = 20Hz to 20kHz	150			W
Total harmonic distortion	THD	Po = 1.0W, f = 1kHz			0.008	%
Frequency response	f _L , f _H	Po = 1.0W, $^{+0}_{-3}$ dB		20 to 50k		Hz
Input impedance	r _i	Po = 1.0W, f = 1kHz		55		kΩ
Output noise voltage	V _{NO} *	$V_{\rm CC}$ = ± 72 V, Rg = 10 k Ω			1.2	m∀rms
Neutral voltage	V _N	V _{CC} = ±72V	-70	0	+70	mV

Notes.

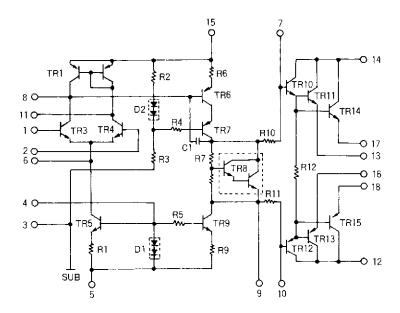
For power supply at the time of test, use a constant-voltage power supply unless otherwise specified.

*The output noise voltage is represented by the peak value on rms scale (VTVM) of average value indicating type. The noise voltage waveform includes no flicker noise. For measurement of the output noise voltage, use the specified transformer power supply shown right.

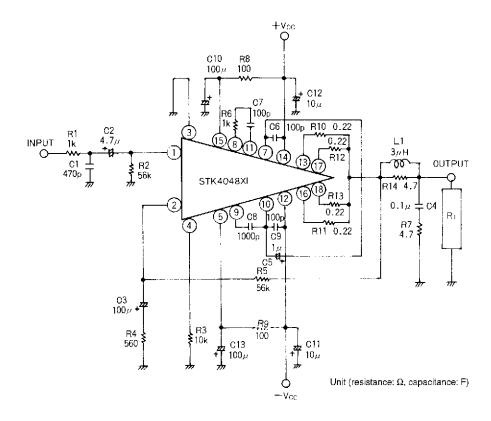


Specified Transformer Power Supply (Equivalent to MG250)

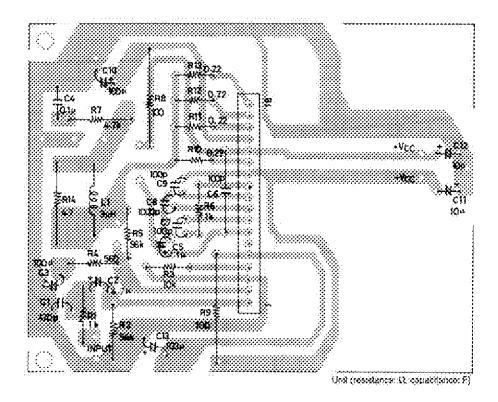
Equivalent Circuit

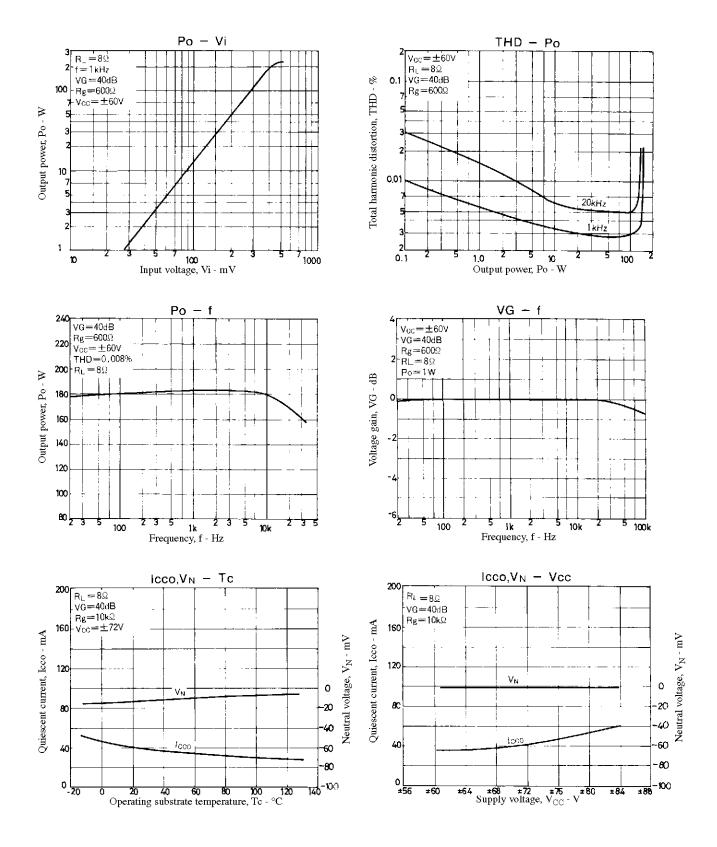


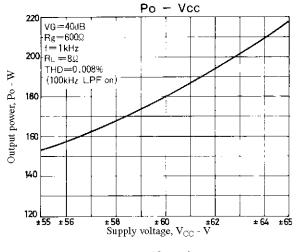
Sample Application Circuit: 150W min Single-Channel AF Power Amplifier

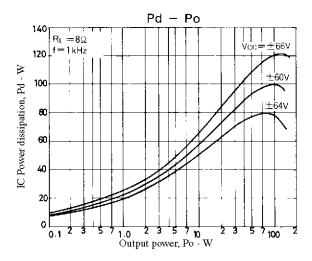


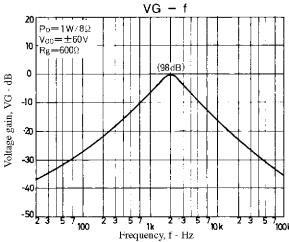
Sample Printed Circuit Pattern for Application Circuit (Cu-foiled side)



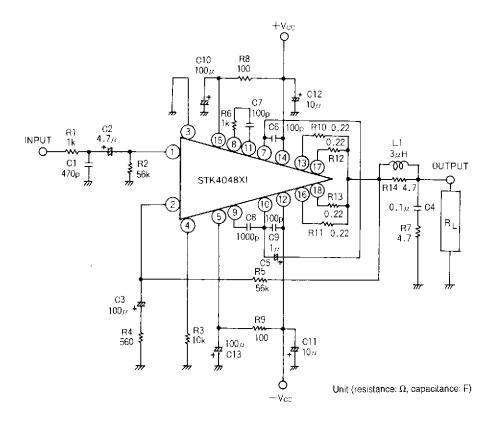








Description of External Parts



R1, C1	Input filter circuit • Used to reduce noise at high frequencies.		
C2	Input coupling capacitor • Used to block DC current. When the reactance of the capacitor increases at low frequencies, the dependence of 1/f noise on signal source resistance causes the output noise to worsen. It is better to decrease the reactance.		
R2	Input bias resistor • Used to bias the input pin to zero. • Affects V _N stability. (See NF circuit.) • Because of differential input, this resistor fixes the input resistance practically.		
R4, R5 C3 (C2)	NFB circuit (AC NF circuit). It is desirable that the error of the resistor value is 1% or less. NFB circuit (AC NF circuit). It is desirable that the error of the resistor value is 1% or less. $C3 : Capacitor for AC NF R4, R5 : Used to set VG$ • VG setting obtained by using R4, R5		
R3	First-stage constant-current bias resistor		
R6, C7	Used for oscillation blocking and phase compensation		
R7, C4	Used for oscillation blocking and phase compensation (C4 : A polyester film capacitor is recommended.)		
C6, C9	Used for oscillation blocking and phase compensation (Must be connected near the pin) C6 : Power amp on (+) side C9 : Power amp on (-) side		
C4	Used for oscillation blocking and phase compensation (Used for oscillation blocking before clip)		
C5	Used for oscillation blocking and distortion improvement		
C8, C10	Ripple filter circuit on (+) side		
R9, C13	Ripple filter circuit on (–) side		
C11, C12	Used for oscillation blocking • Used to decrease the power supply impedance to operate the IC stably. Must be connected near the IC pin. It is desirable to use an electrolytic capacitor.		
L1, R14	Used for oscillation blocking		
R10, R11 R12, R13	Output limiting resistors		

Thermal Design

The IC power dissipation of the STK4048XI at the IC-operated mode is 100W max. at load resistance 8Ω for continuous sine wave as shown in Figure 1.

In an actual application where a music signal is used, it is impractical to estimate the power dissipation based on the continuous signal as shown right, because too large a heat sink must be used. It is reasonable to estimate the power dissipation as 1/10 Po max. (EIAJ).

That is, Pd = 65W at 8Ω

Thermal resistance θ c-a of a heat sink for this IC power dissipation (Pd) is fixed under conditions 1 and 2 shown below.

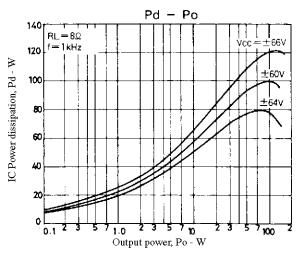


Figure 1. STK4048XI Pd – Po $(R_1 = 8\Omega)$

Condition 1: $Tc = Pd \times \theta c - a + Ta \le 125^{\circ}C$ (1)

where Ta: Specified ambient temperature

Tc: Operating substrate temperature

Condition 2: $T_j = Pd \times (\theta c-a) + Pd/4 \times (\theta j-c) + Ta \le 150$ °C(2)

where Tj: Junction temperature of power transistor

Assuming that the power dissipation is shared equally among the four power transistors, thermal resistance θj -c is $1.2^{\circ}C/W$ and

$$Pd \times (\theta c - a + 1.2/4) + Ta \le 150^{\circ}C$$
....(3)

Thermal resistance θ c-a of a heat sink must satisfy inequalities (1) and (3).

Figure 2 shows the relation between Pd and θ c-a given from (1) and (3) with Ta as a parameter.

[Example] The thermal resistance of a heat sink is obtained when the ambient temperature specified for a stereo amplifier is 50°C.

Assuming $V_{CC} = \pm 60V$, $R_L = 8\Omega$,

 $R_{L} = 8\Omega$: Pd = 65W at 1/10 Po max.

The thermal resistance of a heat sink is obtained from Figure 2.

 $R_L = 8\Omega : \theta c - a1 = 1.15$ °C/W

Tj when a heat sink is used is obtained from

 $R_{L} = 8\Omega : Tj = 144.3^{\circ}C$

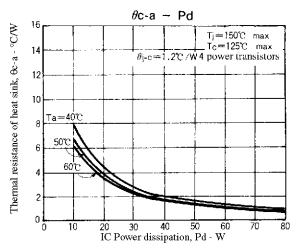


Figure 2. STK4048XI θc-a – Pd

This design is based on the use of a constant-voltage regulated power supply. Pd differs when a transformer power supply is used. Redesign must be made based on Pd that suits the regulation of each transformer.

- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
 - Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees, jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of July, 1997. Specifications and information herein are subject to change without notice.